

# Ka Band, Low Noise Amplifier

## 27.0 - 31.5 GHz



**MAAL-011240**

Rev. V1

### Features

- Low Noise Figure: 1.5 dB
- Gain: 25.5 dB
- P1dB: 18 dBm
- OIP3: 27 dBm
- Bias Voltage:  $V_{DD} = 3.5$  V
- Bias Current:  $I_{DSQ} = 90$  mA
- 50  $\Omega$  Matched Input and Output
- 3 mm AQFN-12LD Package
- RoHS\* Compliant

### Applications

- Satellite Communications
- Low Earth Orbit Space Payloads
- GEO High Throughput Satellite
- Radar
- EW

### Description

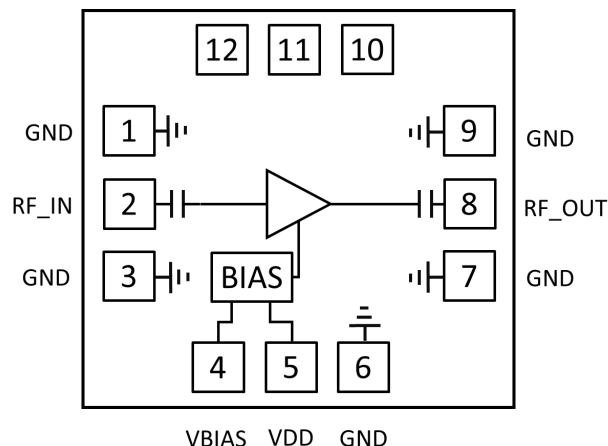
The MAAL-011240 is an easy to use low noise amplifier. It operates from 27 to 31.5 GHz and provides 1.5 dB noise figure, 25.5 dB gain and a P1dB of 18 dBm. The input and output are fully matched to 50  $\Omega$  with typical return loss >12 dB. This part is packaged in a 3 mm AQFN-12LD package.

This product is fabricated using a GaAs pHEMT process which features full passivation for enhanced reliability.

The MAAL-011240 can be used as a low noise amplifier stage or as a driver stage in higher power applications. This device is ideally suited for Ka-band communication systems.

The MAAL-011240 is also available in die form under MAAL-011240-DIE part number.

### Functional Schematic



### Pin Configuration

Pin #	Function	Description
1,3,6,7,9	GND	Ground
2	RF <sub>IN</sub>	RF Input
4	VBIAS	Bias Voltage
5	VDD	Drain Supply
8	RF <sub>OUT</sub>	RF Output
10,11,12	NC	Not Connected <sup>2</sup>
Paddle	GND <sup>3</sup>	Ground

2. These pins are not connected internally. MACOM recommends these are grounded on the application PCB.

3. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

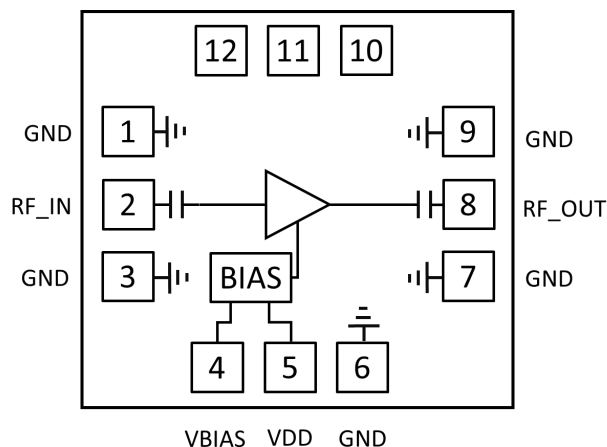
### Ordering Information<sup>1</sup>

Part Number	Package
MAAL-011240-TR1000	1000 piece reel
MAAL-011240-TR3000	3000 piece reel
MAAL-011240-SB1	Sample Board

1. Reference Application Note M513 for reel size information.

<sup>1</sup> \* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

### Pin Configuration and Functional Descriptions



Pin #	Pin Name	Description
1,3,6,7,9	GND	These pins are grounded internally. It is recommended these are grounded on the application PCB.
2	RF_IN	RF Signal Input. This pad is matched to 50 $\Omega$ and is AC coupled
4	VBIAS	A voltage can be applied to this pin to set the required IDSQ as described in the application section
5	VDD	Drain bias for the amplifier. External bypass capacitors are required as described in the applications schematic.
8	RF_OUT	RF Signal Output. This pad is matched to 50 $\Omega$ and is AC coupled. There is a shunt inductor to ground providing a DC ground path.
10,11,12	N/C	These pins are not connected internally. MACOM recommends these are grounded on the application PCB.
Paddle		RF, DC and thermal ground

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**Electrical Specifications: Freq. = 27.0 - 31.5 GHz,  $T_A = 25^\circ\text{C}$ ,  $V_D = 3.5\text{ V}$ ,  $Z_0 = 50\ \Omega$**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Small Signal Gain	$P_{IN} = -20\text{ dBm}$ 27.0 GHz 31.5 GHz	dB	23.0 23.5	25.0 25.5	—
Small Signal Gain Variation over Temperature	—	dB/ $^\circ\text{C}$	—	0.02	—
Gain Flatness	—	dB	—	0.5	—
Noise Figure	—	dB	—	1.5	—
Input Return Loss	—	dB	—	10	—
Output Return Loss	—	dB	—	10	—
P1dB	27.0 GHz 31.5 GHz	dBm	16 16	18 18	—
Output 3rd Order Intercept	$P_{IN} = -18\text{ dBm/tone}$ , 10 MHz spacing	dBm	—	27	—
Supply Current	—	mA	—	90	—

### Absolute Maximum Ratings<sup>4,5</sup>

Parameter	Absolute Maximum
Input Power	20 dBm
Drain Voltage	5 V
Junction Temperature <sup>6,7</sup>	+160 $^\circ\text{C}$
Operating Temperature	-40 $^\circ\text{C}$ to +85 $^\circ\text{C}$
Storage Temperature	-65 $^\circ\text{C}$ to +125 $^\circ\text{C}$

4. Exceeding any one or combination of these limits may cause permanent damage to this device.
5. MACOM does not recommend sustained operation near these survivability limits.
6. Operating at nominal conditions with  $T_J \leq +150^\circ\text{C}$  will ensure MTTF >  $1 \times 10^6$  hours.
7. Junction Temperature ( $T_J$ ) =  $T_C + \Theta_{jc} \cdot (V \cdot I)$   
Typical thermal resistance ( $\Theta_{jc}$ ) = 66.5  $^\circ\text{C/W}$ .
  - a) For  $T_C = +25^\circ\text{C}$ ,  
 $T_J = 50.6^\circ\text{C}$  @ 3.5 V, 110 mA
  - b) For  $T_C = +85^\circ\text{C}$ ,  
 $T_J = 110.6^\circ\text{C}$  @ 3.5 V, 110 mA

### Maximum Operating Conditions

Parameter	Maximum
Input Power	0 dBm
$V_{DD}$	4.5 V
Junction Temperature <sup>6,7</sup>	+150 $^\circ\text{C}$
Operating Temperature	-40 $^\circ\text{C}$ to +85 $^\circ\text{C}$

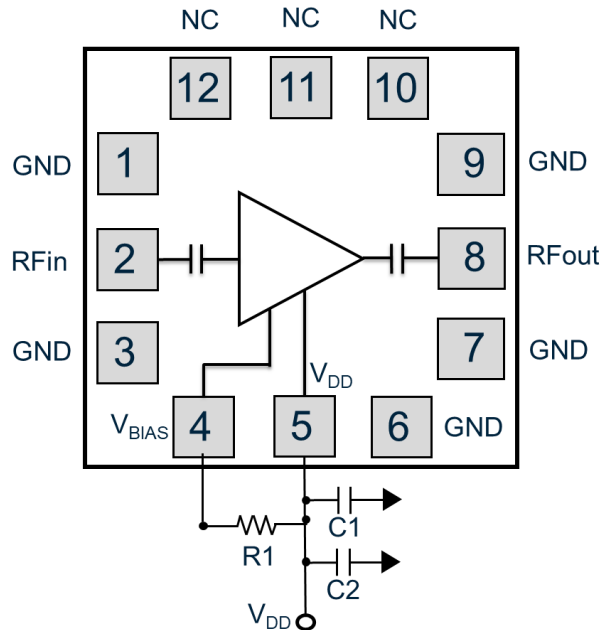
### Handling Procedures

Please observe the following precautions to avoid damage:

### Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1A (250 V), Class C2a (500 V) CDM devices.

Application Schematic



Application Circuit and Operation

The basic application circuit is shown below. Place C1 capacitor as close to the package as physically possible. The position of the C2 capacitor is not as critical but should also be placed as closely as practically possible.

To ensure proper grounding the number of ground vias under the device should be maximized (within practical limits imposed by the PCB vendor).

Set IDQ by adjusting R1

The value of R1 sets IDQ according to the table below:

R1 ( $\Omega$ )	IDQ (mA)
3.5k	45
2.9k	50
2k	60
1.5k	70
1.2k	80
900	90
800	100
690	110
600	120

Parts List

Part	Value	Case Style
C1	100 pF	0402
C2	0.1 $\mu$ F	0402
R1	-	0402

Operating the MAAL-011240

Turn-on

1. Apply  $V_D$  (+3.5 V)
2. Apply  $RF_{IN}$  signal

Turn-off

1. Remove  $RF_{IN}$  signal.
2. Decrease  $V_D$  to 0 V

# Ka Band, Low Noise Amplifier

## 27.0 - 31.5 GHz

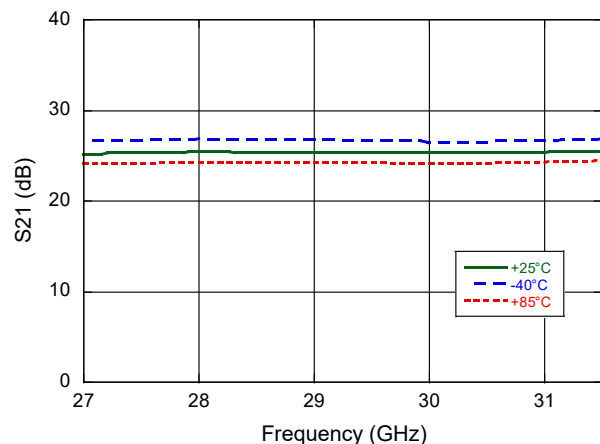


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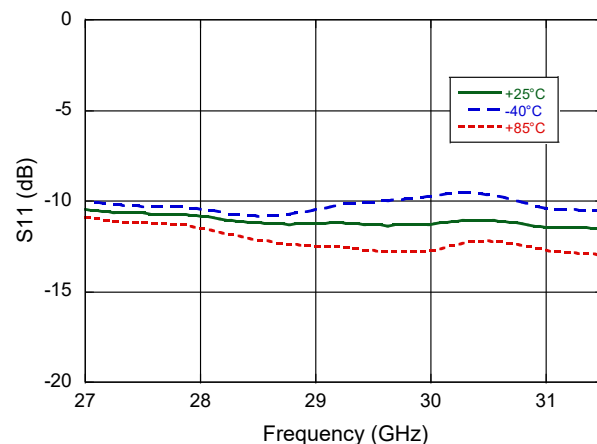
Rev. V1

Typical Performance Curves @  $V_D = 3.5$  V,  $I_D = 90$  mA,  $Z_0 = 50$   $\Omega$

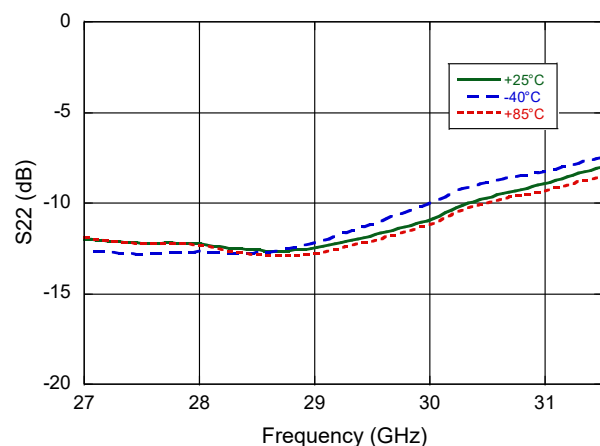
Gain



Input Return Loss



Output Return Loss



# Ka Band, Low Noise Amplifier 27.0 - 31.5 GHz

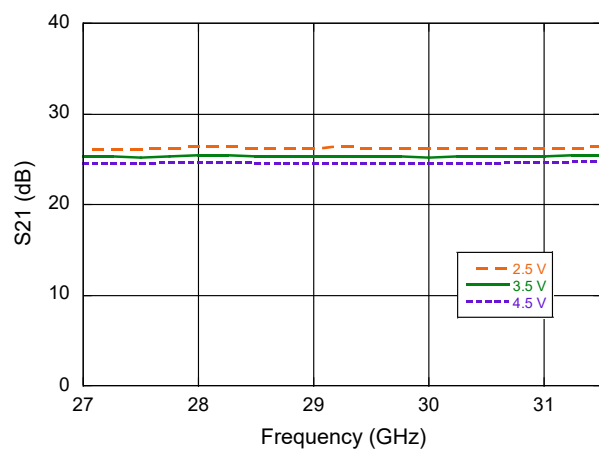


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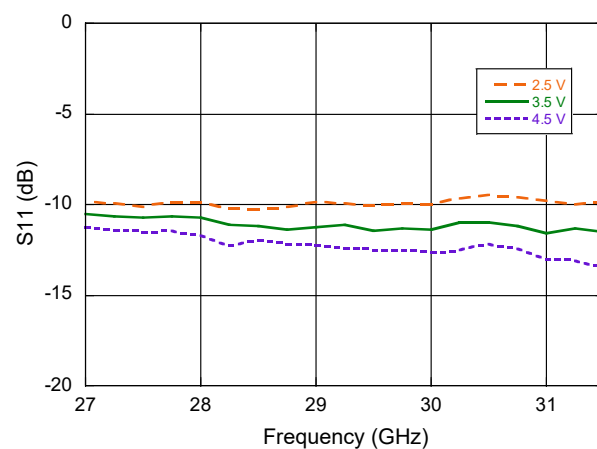
Rev. V1

## Typical Performance Curves @ $I_D = 90 \text{ mA}$ , $Z_0 = 50 \Omega$

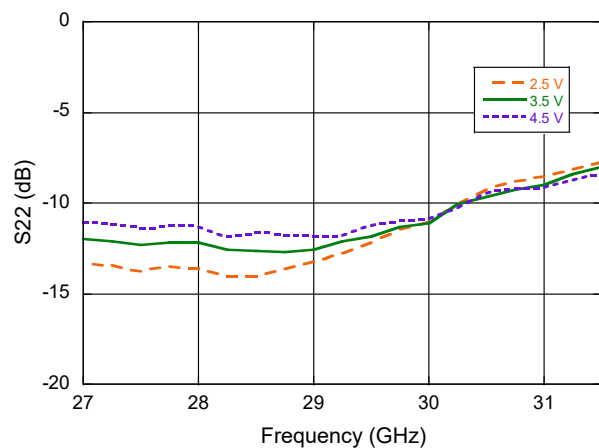
### Gain



### Input Return Loss



### Output Return Loss



# Ka Band, Low Noise Amplifier 27.0 - 31.5 GHz

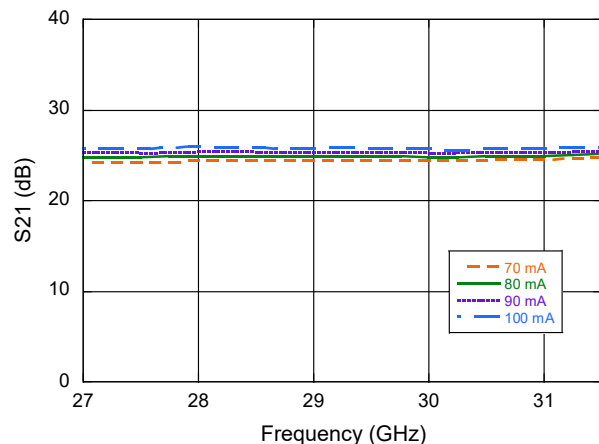


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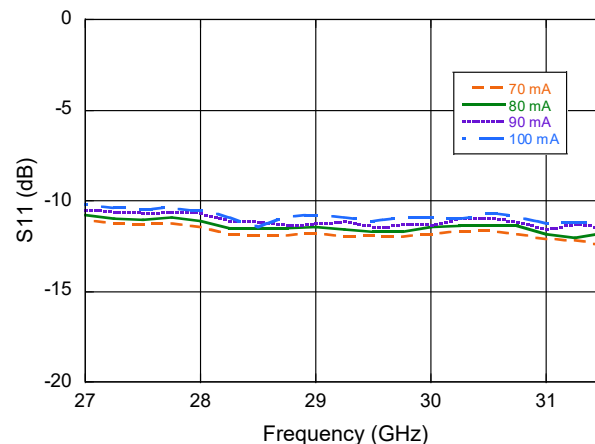
Rev. V1

## Typical Performance Curves @ $V_D = 3.5$ V, $Z_0 = 50$ $\Omega$

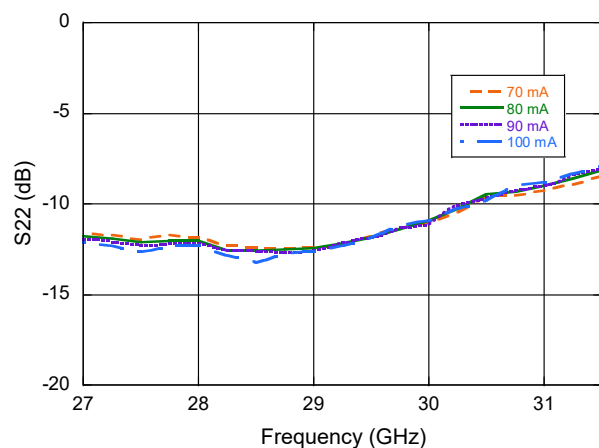
**Gain**



**Input Return Loss**



**Output Return Loss**



# Ka Band, Low Noise Amplifier 27.0 - 31.5 GHz

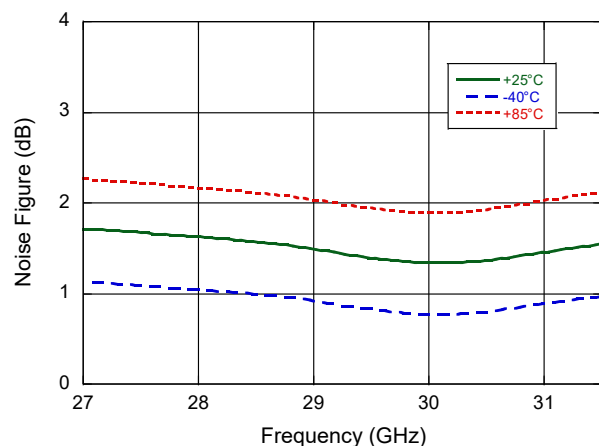


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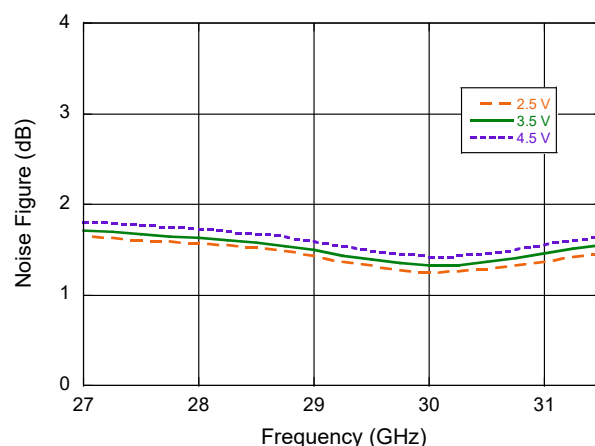
Rev. V1

## Typical Performance Curves @ $V_D = 3\text{ V}$ , $I_D = 90\text{ mA}$ , $25^\circ\text{C}$ , $Z_0 = 50\ \Omega$

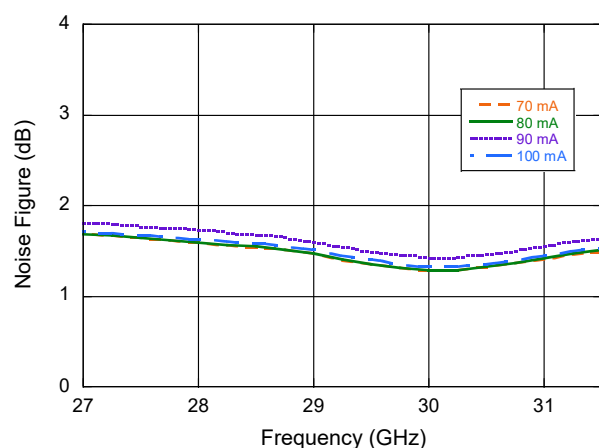
Noise Figure over Temperature



Noise Figure over Voltage



Noise Figure over Current





# Ka Band, Low Noise Amplifier 27.0 - 31.5 GHz

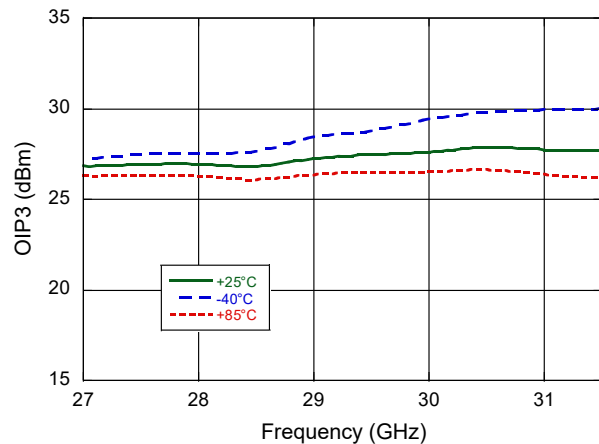


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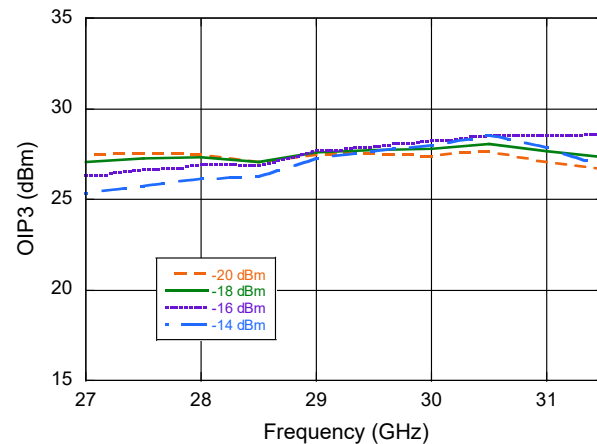
Rev. V1

Typical Performance Curves @  $V_D = 3\text{ V}$ ,  $I_D = 90\text{ mA}$ ,  $P_{IN} = -18\text{ dBm}$ ,  $25^\circ\text{C}$ ,  $Z_0 = 50\ \Omega$

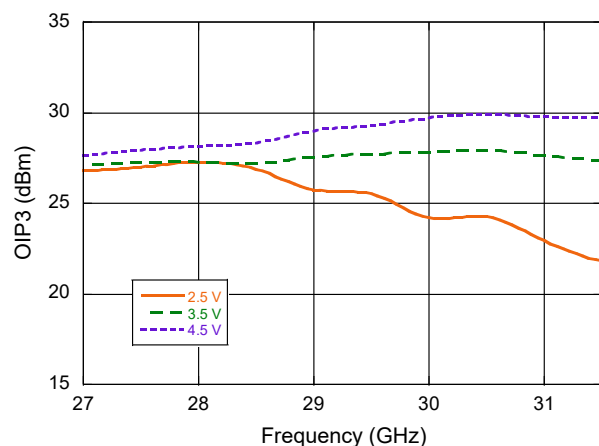
**OIP3 over Temperature**



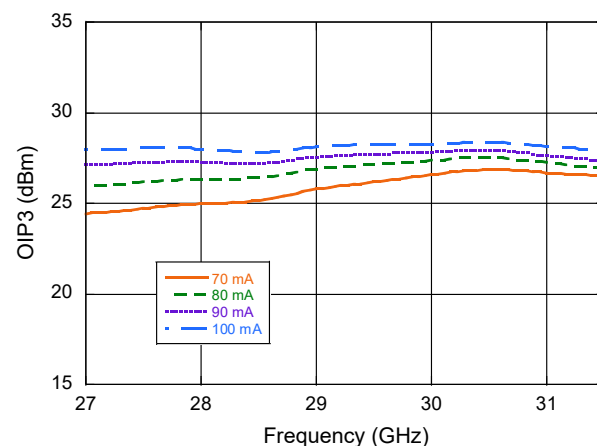
**OIP3 over Input Power**



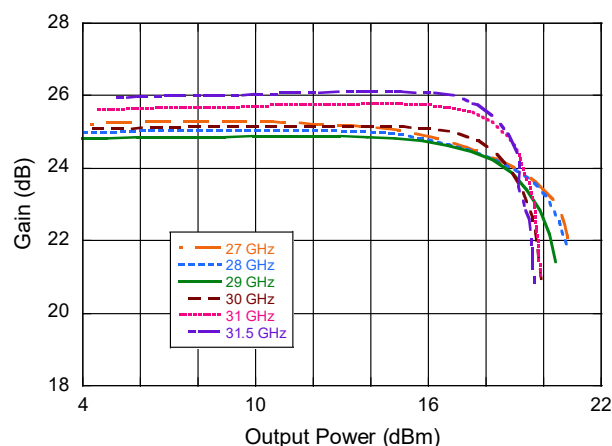
**OIP3 over Bias Voltage**



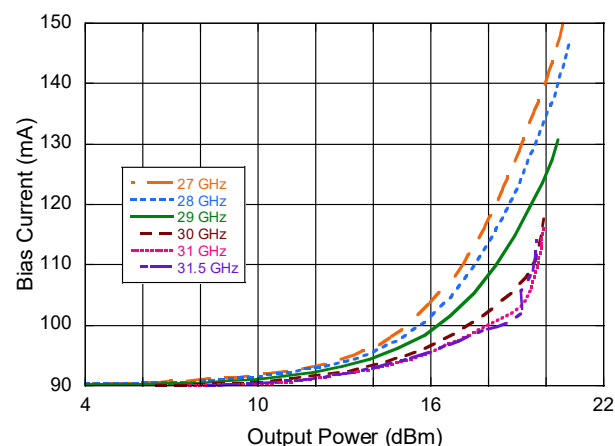
**OIP3 over Bias Current**



**Gain vs Output Power over Frequency**



**Bias Current vs Output Power over Frequency**



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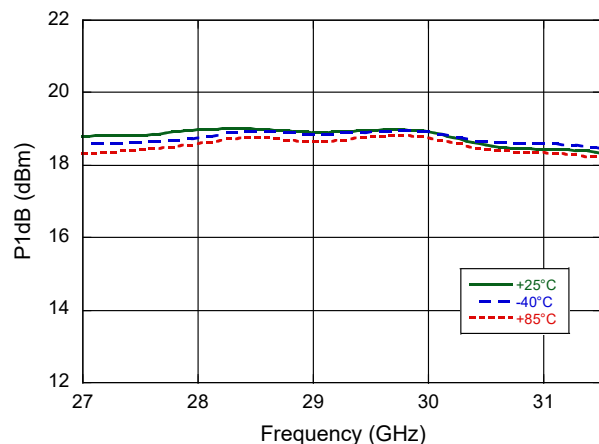


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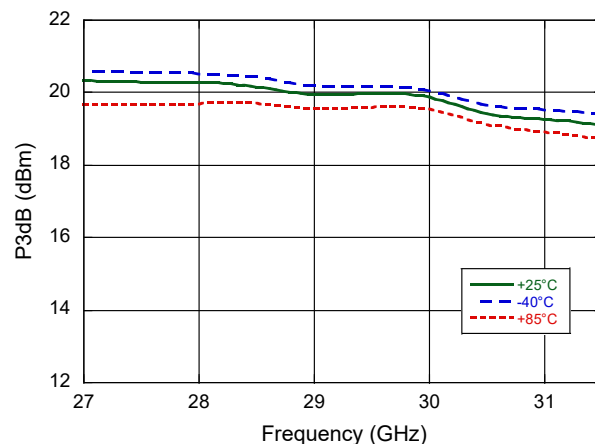
Rev. V1

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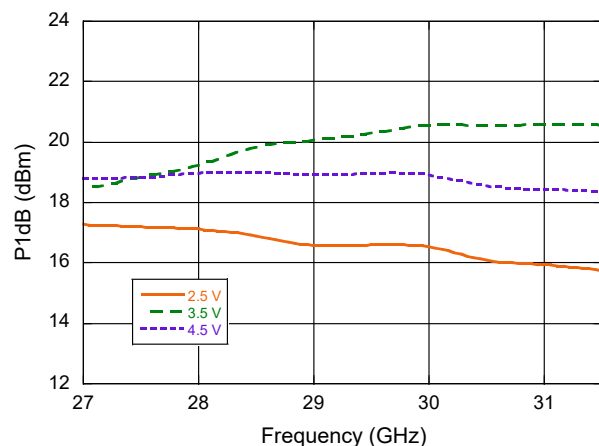
**P1dB over Temperature**



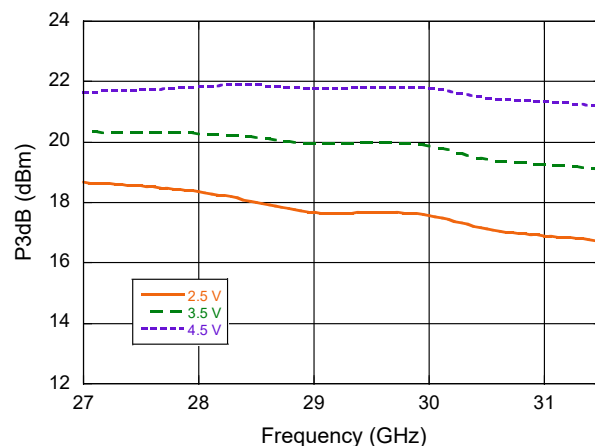
**P3dB over Temperature**



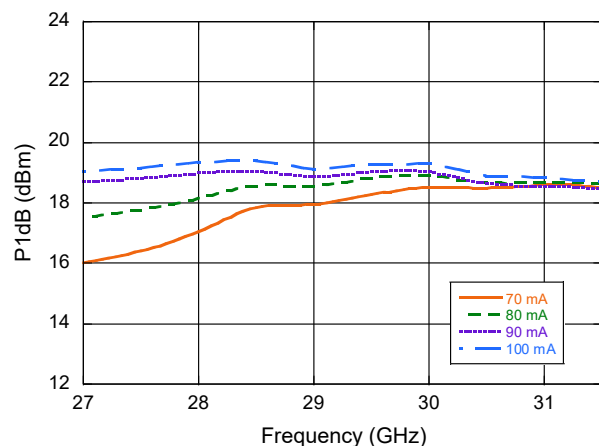
**P1dB over Bias Voltage**



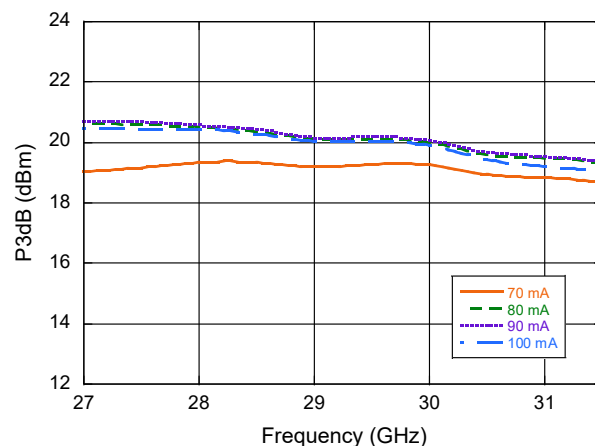
**P3dB over Bias Voltage**



**P1dB over Bias Current**



**P3dB over Bias Current**



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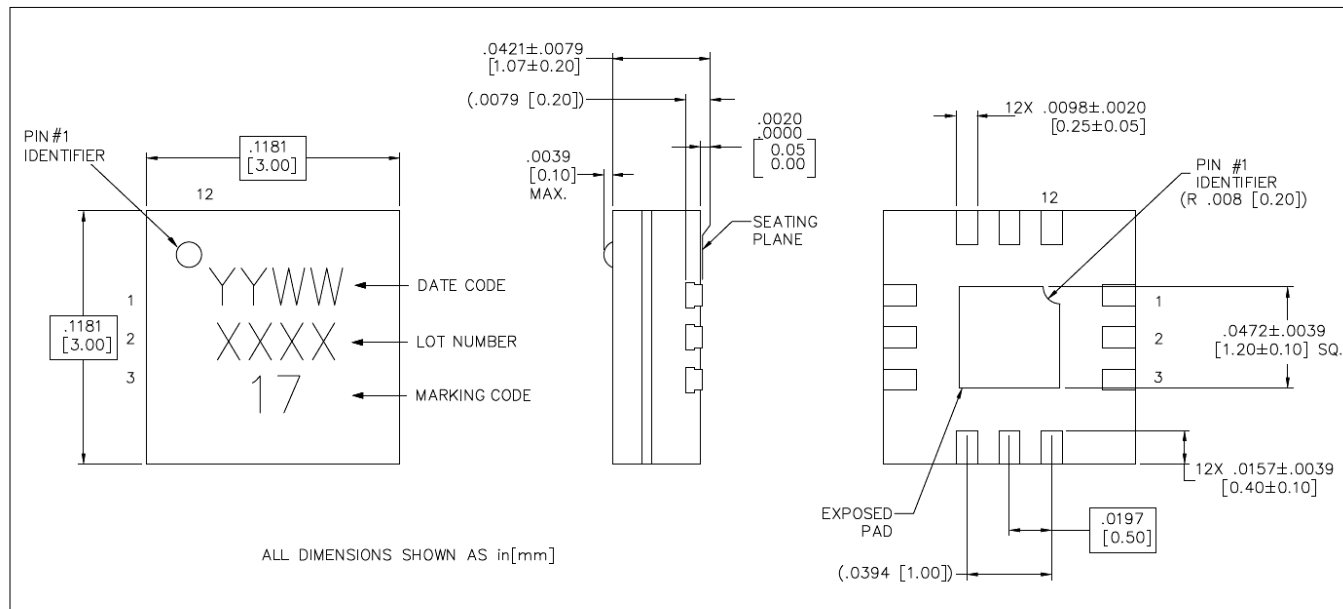
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### Lead-Free 3 mm AQFN-12LD <sup>8,9,10,11,12</sup>



8. All units in in(mm), unless otherwise noted, with a tolerance of .xxxx =  $\pm 0.0005$  in and .xxx =  $\pm 0.005$  in.
9. Lead finish: NiPdAu plating
10. Marking: line 1 yyww = date code, line 2 wafer lot number; line 3 part number
11. Reference Application Note S2083 for lead-free solder reflow recommendations.
12. Meets JEDEC moisture sensitivity level 3 requirements.

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